

1110-97825 PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Appl. No.	: 10/586,445)	Confirmation No.: 4877
Applicant	: NAKAMURA et al.)	
Filed	: 17 July 2006)	DO NOT ENTER: /RK/
Art Unit	: 1792)	11/29/2010
Examiner	: KUNEMUND)	
Docket No.	: 1110-97825)	
Customer No.:	24628)	
Title: METHOD FOR PREDICTING) PRECIPITATION BEHAVIOR OF OXYGEN) IN SILICON SINGLE CRYSTAL, METHOD) FOR DETERMINING PRODUCTION) PARAMETER OF SILICON SINGLE) CRYSTAL, AND STORAGE MEDIUM FOR) STORING PROGRAM FOR PREDICTING) PRECIPITATION BEHAVIOR OF OXYGEN) IN SILICON SINGLE CRYSTAL)			

Commissioner for Patents
P.O. Box 1450
Alexandria, Virginia 22313-1450

AMENDMENT

Dear Sir:

The Office Action of 19 August 2010 has been carefully reviewed and the following amendments and remarks are made in response thereto:

Amendments to the Claims begin on page 2 of this paper.

Remarks/Arguments begin on page 8 of this paper.